

Index

- ABS *see* Andreev bound states
ABS energy 62, 66, 72
acoustic mismatch model (AMM) 315, 332
ADF *see* Amsterdam density functional
AFM *see* atomic force microscope
AMM *see* acoustic mismatch model
Amsterdam density functional (ADF) 170, 171, 181, 191, 203
anchoring groups 147, 152, 234, 239, 246, 247, 249–251, 253, 256, 379
Andreev bound states (ABS) 61, 62, 67–72, 245
atomic force microscope (AFM) 7, 9, 10, 24, 319, 328

backbones 133, 137
 alkane 133
 hydrocarbon chain 213
 molecular 117, 141, 142, 214, 217
 polyethylene glycol 384
BAEs *see* bistricyclic aromatic enes
bias 121–124, 144, 173, 178, 180, 241, 251, 270, 279, 281, 286, 294, 346, 347, 353, 361–364
 negative 266, 268, 281
 positive 266, 268, 269
 source–drain 21, 362
 temperature 330
 zero 102, 275, 277, 287
bias ramps 287, 288, 291
bias scans 275, 287
bias voltage 93, 94, 103, 106, 173, 251, 252, 265, 266, 268, 270, 273–275, 278, 286, 287, 289, 291, 294, 308
binding 118, 129, 130, 135–137, 142, 157, 221, 253, 254, 383
 molecule–electrode 134, 138, 145
 monothiolate 220
bistricyclic aromatic enes (BAEs) 267
bonds 128, 138, 143, 192, 193, 206, 216, 221, 222, 225, 228, 260, 326, 356
 chemical 17, 228, 290, 320
 double 267, 268
 ionic 214
 molecular 127
Brillouin zone (BZ) 91, 105
BZ *see* Brillouin zone

capacitances 400, 403–406, 409
capacitor 400, 402, 404–408, 412, 414, 416–418
carbon nanotubes 3, 17, 24, 31, 145
chains 101, 102, 119, 134–136, 214, 316, 317
 alkyl 217, 225
 backbone/main 210

- carbon 226
- finite ballistic gold 105
- hydrocarbon 218
- infinite gold 105
- infinite linear gold 104
- linear carbon 128
- molecular 146
- charge 34, 125, 156, 158, 213, 274, 295, 319, 398, 399, 402, 404–406, 408, 410, 412–416, 419
 - electronic 304
 - elementary 274, 413
 - negative 187, 213
 - single-electron 400, 414
- charge carriers 35
- charge density 51, 183
- charge distribution 402, 408
- charge states 156, 234, 236
- charge transfer 142, 143, 162, 302, 358
 - continuous 413
 - direct 34
 - fractional 33
- charge transport 34, 37, 42, 145, 147, 200, 203, 239, 300, 302, 323, 324, 328, 329, 332, 342, 398
- charging energies 21, 23, 33, 60, 398, 400
- circuit 13, 43, 374, 398, 400, 402–407, 409, 410, 412–414, 416–418
 - electrical 140
 - electrical short 375
 - electronic 18, 140, 145, 257, 398, 400, 416
 - integrated 2
 - integrated molecular 138
 - logic 417
- circuit models 397, 414–416, 420
 - capacitive 397
 - electronic 417
 - impulse 398
- circuitry 407, 410, 412, 413, 417
- conductance 85–93, 100–103, 105–110, 117–119, 122–124, 127, 128, 132–134, 137, 139–144, 147, 148, 233–235, 326, 342, 344, 351–354
 - background 180
 - device 119, 139
 - differential 100, 178, 190
 - electrical 300, 326, 327
 - experimental 87
 - inelastic 103, 109
 - light-controlled 260, 379
 - off-resonance 190
 - symmetric 102
 - telegraphic 266
 - voltage-induced 241
 - voltage-triggered 241
 - zero-bias 85, 87
- conductance quantum 19, 36, 84, 85, 124
- conductance traces 11, 12, 19–21, 86, 87
- conducting molecule 9, 153, 208, 209, 227, 352
- conductivity 10, 11, 19, 119
 - electrical 236, 300
- configurations 87, 130, 190, 191, 193, 217, 218, 247, 303, 304, 322, 383, 388
 - all-trans* 132
 - bridge-site 190–192
 - hollow-site 190, 191, 193
 - low-spin 241
 - molecular 134
 - side-to-side 383
 - tetrahedral 190
 - transistor 227
- conjugated molecules 183, 346, 348, 352, 364
- contact conductance 8, 86, 127
- contact geometry 122, 127, 129, 131, 133, 135, 137, 181, 186, 190, 192

- contact resistance 118, 120, 127, 128, 131, 134, 136, 138, 142, 150, 329
- contacts 2, 3, 10, 33, 85–88, 91, 92, 127, 142–144, 183–185, 302–305, 307–310, 312, 313, 317, 318, 322, 327, 331–333
- air-stable 327
- bad 92
- close 7
- continuous 307
- hard 142
- identical 308
- inorganic 300
- long-lifetime 127
- mechanical 118, 138, 328
- molecular-scale 32
- molecular-size 34
- robust 122
- weak 236
- contributions 66, 82, 189, 193, 282, 301, 305, 348, 360, 361, 413
 - asymmetric 101
 - continuum 72
 - dominant 165, 301
 - relative 291
- Coulomb blockade 111, 174, 178, 343, 397–402, 409, 410, 417
- Coulomb energy 398, 401, 406
- Coulomb oscillations 403, 412, 414
- coupling 33, 34, 36, 37, 39, 40, 42, 51, 63, 64, 67, 68, 124, 125, 127, 139–141, 143–145, 173, 174, 185–187, 195, 196, 399
 - asymmetric 313
 - electromechanical 128
 - electron-vibration 83, 99, 107
 - electron-vibron 289
 - intermode 281
 - lateral 138, 147
 - mechanical 120, 140
 - metal-metal 186
 - plasmonic 383
- critical voltage 398, 402–404, 406–415, 417
- density-functional theory (DFT) 2, 79–81, 83, 85, 88, 90, 92, 95–98, 102, 104, 107, 110, 157, 159, 171
- density of states 55, 56, 62
- destructive interference 58, 342, 345, 346, 348, 350, 352, 353, 356, 359
- device fabrications 23, 118, 207, 373
- devices 6, 7, 13–17, 19–24, 31, 32, 51, 52, 80, 117, 118, 138, 234, 241, 242, 245, 255, 266, 299, 300, 371–373
- break-junction 143
- conventional energy 331
- conventional semiconductor 118
- crossbar 242
- deterministic 265
- electromigration 14, 25
- gated 236
- hybrid 300
- long-lifetime 118, 138
- mechanical transport 130
- mobile 1
- molecular break junction 12
- monolayer 375
- naked break junction 19
- solid-state 260, 397, 399, 420
- three-terminal 6, 21, 201, 240, 241, 398
- two-terminal 6, 51
- DFT *see* density-functional theory
- diffuse mismatch model (DMM) 315, 316, 332
- Dirac point 51, 52, 57–60
- DMM *see* diffuse mismatch model

- electrodes 2, 3, 5–7, 11–13, 15, 83–85, 92–95, 120–125, 127–130, 135–143, 244–247, 251–253, 256, 328–332, 356–358, 399, 400
- bulk 190
- carbon 138
- graphene 2, 17
- metal 320, 321, 323, 328, 329, 331, 372
- microfabricated 18
- miniscule 372
- naked 21
- nanometer-spaced 241
- nanosized 13
- platinum bottom 245
- semi-infinite 101
- electrode separations 20, 86, 87, 90, 107, 139, 144
- electrode surfaces 120, 130, 138–141
- electron density 51, 81, 91, 162, 211, 212, 324
- electronic conductance 302, 304, 305, 308, 311, 333
- electronic coupling 7, 120, 141, 172
- electronic devices 1, 146, 203, 204, 206, 255, 347, 372, 374
- electronic structure 2, 79, 80, 107, 110, 120, 145, 301, 302
- electronic transitions 162–165, 175, 180, 183, 189, 197
- electron–phonon coupling 194
- electron transport 2, 31, 33–42, 44, 46, 48, 50, 72, 79, 80, 84–86, 92, 94–96, 100–102, 104–106, 150, 151
- electron tunnels 295, 400–402, 407, 416, 420
- equilibrium geometry 156, 159, 160, 163, 189
- equilibrium positions 164–166, 180, 194, 197, 277, 278, 295
- Fermi–Dirac distribution 35, 309, 310, 314
- Fermi energy 51, 52, 102, 104, 120, 122, 123, 133, 135, 142, 143, 173, 174, 178, 186, 309, 350–353, 358, 361–363
- Fermi level 51, 61, 64, 67, 85, 93, 102, 104, 303, 411
- forces 10, 87, 208–211, 228
 - basic 7
 - breakdown 134
 - capillary 387
 - hydrophobic 377
 - intermolecular noncovalent 374
 - intramolecular 209, 222, 228
 - ion–dipole 211
 - molecular 10
 - stochastic 271
- Franck–Condon principle 295
- gap 5, 6, 11, 13, 18, 20, 39, 51, 234, 283, 372, 377, 379, 384, 386, 388
- gate 14, 50–52, 58, 62, 178, 180, 236, 241, 252, 362
- gate electrode 6, 13, 62, 173, 234, 239, 399
- gate voltages 21, 59–61, 173, 178, 180, 240, 251, 252, 410, 417
- gold electrodes 131, 135, 137, 138, 143, 148, 152, 236, 249, 253, 285, 290, 345, 389
 - macroscopic 17
 - prefabricated 380
- gold nanorods 381
- gold surfaces 101, 208, 209, 215, 217, 221–223, 226, 228, 260, 374
- graphene 3, 16, 24, 31, 33, 34, 43, 50–53, 55, 57–59, 73, 145, 209, 227, 228

- Green's functions 39–42, 44, 46, 50, 57, 63, 65, 72, 84, 98, 360
 - electronic 64, 70
 - energy-dependent surface 58
 - inelastic retarded 188, 198
 - nonequilibrium 2, 34, 39, 79, 80, 184, 185
 - noninteracting retarded 98
 - reservoir 40
 - uncoupled system 50
- highest occupied molecular orbital (HOMO) 52, 90, 117, 119, 134, 183, 302, 303, 308, 312, 313, 318, 323–326, 333, 358–361
- HOMO *see* highest occupied molecular orbital
- IETS *see* inelastic electron tunneling spectroscopy
- inelastic effects 80, 95, 110
- inelastic electron tunneling spectroscopy (IETS) 93–95, 131, 149, 150, 189, 197, 199
- inelastic processes 39, 185, 187–190
- inelastic transmission 187–189, 193
- interactions 33, 40, 97, 106, 110, 124, 125, 209–211, 213, 214, 268, 274, 300, 307, 373, 412, 417
 - base-pair 206
 - capacitive 185
 - chemical 6, 320
 - dipole–dipole 211, 212
 - donor–acceptor 235
 - electron–electron 33, 343
 - electronic 194, 368
 - electron–oscillator 67
 - electron–phonon 150, 152, 204
 - electrostatic 274
 - gold–gold 215
 - hydrophobic 382
 - ion–ion 82
 - metal–ligand 206
 - molecule–electrode 246
 - noncovalent 206, 374
- interface 3, 205, 206, 210, 212, 214, 216, 218, 220, 222, 224, 226, 228, 314–316, 377, 389
 - atomic-scale 85
 - gold–sulfur 215
 - metal–dielectric 383
 - metal–molecule 373
 - molecule–electrode 2
 - molecule–to–electrode 3, 264, 286
- interference 69, 343, 345, 347–349, 352, 354, 357–363, 365
 - constructive 359
 - double-peak 60
- interference effects 50, 341–349, 351, 352, 354–357, 359, 361–364
- intermolecular forces 210, 214, 377
- junction 85, 86, 90–96, 141–144, 172, 173, 244, 265–267, 301–304, 307–310, 317, 318, 326–328, 330–333, 352, 353, 402, 403, 409, 411–415
 - atomic-scale 330
 - dimer 383
 - fullerene 275, 326
 - nanometer-sized 383
 - nonideal 307
 - self-assembled 381
- junction capacitance 402, 404, 406, 412, 413, 415–417

- Landauer formalism 309, 331, 332
- Landauer theory 124, 303–305, 315, 323, 330
- Langmuir–Blodgett films 242, 380
- Langmuir–Blodgett technique 378
- lattices 218, 219, 222, 317
 - crystal 221
 - hexagonal 218, 219, 379
 - methanethiolate 221
- layers 81, 87, 89, 375, 377, 378, 382
 - adsorbed water 225
 - dielectric 342
 - molecular 333, 375
 - monomolecular 377
 - native oxide 225
 - spin-coated 387
- linker groups 126–128, 135–138, 140, 142
- lowest-order expansion
 - approach 98, 99
- lowest unoccupied molecular orbital (LUMO) 52, 90, 117, 119, 134, 183, 302, 303, 308, 312, 326–328, 333, 358–361
- LUMO *see* lowest unoccupied molecular orbital
- MCBJs *see* mechanically controlled break junctions
- mechanically controlled break junctions (MCBJs) 5, 11, 85, 128, 319, 372
- metastable state 241, 268, 269, 271, 274, 281–285, 291, 294
- model 109, 110, 120, 121, 123, 126, 131, 139–141, 145, 277, 278, 287–289, 292, 294, 398, 402, 403, 414, 415, 418
 - analytical 121
 - meta-substituted 348
 - qualitative 128
 - single-level 110, 178
 - sliding 142
 - theoretical 143, 222, 272
 - tight-binding 348
- model system 51, 215, 223, 316, 377
- modes 64, 69, 70, 96, 99, 100, 108, 109, 155, 160, 161, 164, 180–183, 189–193, 198, 214, 282, 292, 302
- acetylene 387
 - active 281
 - breathing 193, 282
 - dominant 183, 191
 - low-frequency 155, 183, 190
 - multiple 165
 - normal 157, 160, 164, 170
 - transverse 57
 - vibronic 265, 288, 290, 292, 294
- molecular devices 13, 19, 21, 23, 31, 80, 110, 120, 122, 139, 142, 368, 371, 379, 389, 390
- molecular junctions 2, 4, 121–123, 128–132, 143, 144, 146, 150–154, 199, 200, 299, 300, 302–304, 306–312, 316–334, 367, 368, 371, 376
 - coupled 178, 333
 - planar 51
- molecular levels 34, 36, 40, 50–52, 54–56, 58, 60, 63, 233
- molecular orbitals 32, 33, 89, 92, 120, 130, 135, 138–141, 143, 317, 318, 323, 326, 357, 358, 360, 363, 366
- molecular species 127, 131, 373
- molecular switches 3, 21, 22, 233, 234, 236, 238, 240, 242, 254–256, 258–260, 263–268, 284, 290–292, 294, 344, 361, 362
- molecular systems 2, 4, 14, 118–121, 123, 125–127, 138, 142, 145, 257, 258, 346, 355

- molecular transistors 37, 72, 198, 200
- molecular wires 10, 11, 100, 121, 123–125, 148, 149, 157, 236, 285, 342, 367, 384
- molecule–electrode contact 3, 117, 118, 120, 122, 135, 140, 145, 372
- molecule–electrode coupling 127, 138, 139, 141, 256
- monolayers 150, 208, 210, 215, 216, 226, 228, 242, 249, 250, 319, 330, 375, 377–379, 390
 - alkanethiolate 234
 - insoluble 377
 - ordered 319, 320, 333
 - rotaxane 244
- nanofabrication methods 6, 13, 18
- nanogap electrodes 6, 13–15, 17, 18, 209, 372
- nanogaps 6, 7, 13–15, 17, 18, 25, 57, 208, 234, 268, 283, 285, 372, 373, 383, 384, 388, 389
- nanoparticles 11, 131, 208, 209, 239, 241, 377, 379, 387
 - colloidal 385
 - spherical 390
 - therapeutic 209
- nanorods 17, 381–384
- nanoscale devices 199, 372
- nanoscale junctions 80, 92, 95, 105
- NEGF *see* nonequilibrium Green's function
- nonequilibrium Green's function (NEGF) 2, 79, 80, 83, 85, 95, 102, 184, 185
- orbitals 34, 42, 43, 141, 183, 188, 313, 318, 358, 360, 361, 363, 368
- atom-centered 97
- discrete molecular 312
- dominant molecular 142, 144
- electronic 302
- organic molecules 199, 209, 210, 214, 215, 225, 299, 319–321, 333
- oscillator 40, 63–65, 67–69, 72, 105, 159
- phonons 3, 33, 72, 156, 161, 177, 179, 187, 195, 199, 301, 302, 305, 306, 309, 315, 332
- process 3, 4, 104, 137, 138, 141–143, 174, 175, 210, 214–216, 221–223, 225, 228, 342, 343, 345, 362–364, 371, 377, 378
- bottom-up 373
- coherent 185
- elastic 187
- electronic 345
- higher-order 185
- irreversible 345
- tautomerization 254
- trapping 323
- two-step 399
- properties 7, 31, 38, 117, 118, 175, 234, 249, 260, 307, 315, 344, 345, 347, 364, 402, 409
- catalytic 223
- chemical 102, 209
- cyclic 188
- distinctive 118
- electrical 384, 399
- electromechanical 118
- electronic 118–120, 127, 138, 254, 397
- electronic spectral 98
- intrinsic 92
- physical–chemical 377
- redox 235
- structural 108, 134

- thermoelectric 303, 311, 319, 324, 325
- thermometric 323
- QCM *see* quartz crystal microbalance
- quantum dots 61, 198, 203, 347
- quantum interference 58, 72, 366–368
- quantum transport 33, 35, 81, 148, 201, 367
- quantum tunneling 3, 263, 265, 274, 284
- quartz crystal microbalance (QCM) 223
- recursion relations 165, 167, 169
- recursive Green's function technique 33, 43, 45, 47, 49, 53
- resonance 36, 50, 61, 62, 67–71, 100, 180, 190, 382, 387
 - polariton 72
 - surface plasmon 223
- SAMs *see* self-assembled monolayers
- scanning tunneling microscope (STM) 7–10, 15, 24, 85, 100, 101, 128, 131, 151, 156, 199, 203, 204, 222, 234
- scattering 33, 91, 92, 105, 187, 315
 - electron–phonon 33
 - inelastic 65, 93, 204, 315, 343
 - surface-enhanced Raman 383
- SCBA *see* self-consistent Born approximation
- Seebeck coefficient 300, 303, 309, 322, 323, 326, 329, 332
- self-assembled monolayers (SAMs) 93, 95, 205, 207, 209, 210, 212–214, 217–219, 223, 225, 234, 236, 241, 316, 374–377, 380
- self-consistent Born approximation (SCBA) 63, 98, 100, 187
- single-molecule devices 2, 3, 5, 7, 16, 18, 19, 117, 118, 120–122, 126–128, 130, 132, 134–136, 140, 142–145, 397, 398, 400
- single-molecule junctions 128, 129, 137, 138, 147–149, 152, 154–156, 158, 160, 162, 164, 166, 168, 178–180, 184, 319–322, 330
- single molecules 1, 2, 4–6, 8–11, 13, 18, 21–23, 150, 151, 207–209, 320, 321, 342, 343, 367, 372, 380, 381, 383, 384, 397–399
- single-molecule transport 135, 341, 342, 344, 346, 348, 350, 352, 354, 356, 358, 360, 362, 364, 366, 368
- singular value decomposition (SVD) 177
- space 17, 50, 82, 91, 267, 359, 361
 - electron–hole 63, 64
 - electronic 107
 - null 173, 175, 177, 178
- spacer unit 210, 213, 214, 217, 225
 - hydrophobic 225
- states 21, 22, 37, 38, 61, 62, 69, 102–106, 122–125, 163–165, 172, 173, 176, 178, 233, 234, 264–268, 274, 275, 286–292, 344
 - bound 61, 62, 68, 162, 359
 - broken symmetry 32
 - chemical 216

- continuous 312, 331
- continuum 66
- controlled on-off 61
- empty 97, 411
- excited 156, 163, 170, 171, 178, 197
- gas-like 215
- high-conducting 236, 238, 249, 275, 287, 288
- high-current 275
- high-spin 241
- hydroquinone 236
- hysteretic region 281
- low-conducting 233, 236, 238, 249, 287–289
- low-current 275
- low-spin 241
- many-body 33, 172, 177
- neutral 235
- normal 62
- polaritonic 61
- quantized 284
- redox 200, 233, 235, 239, 258
- reservoir 38
- superconducting 64
- transition 274, 293
- vibrational ground 163, 165, 166, 170, 180, 189
- zigzag edge 57–60
- STM *see* scanning tunneling microscope
- STM
 - cryogenic 102
 - low-temperature 93
 - single-molecule 10
 - ultrahigh vacuum 85
- STM-BJ technique 319, 321, 322, 325, 328, 329, 331
- STM break junction method 10, 12
- strain 94, 102, 103, 118, 119, 130, 143, 267
- structure 86, 92, 119, 124, 201, 206, 208, 220, 221, 225, 248, 402, 404, 407, 408, 410, 417
 - crystal 119
 - double-junction 408
 - double-peak 58
 - electron-box 410
 - end-linked 382
 - molecular 15, 19, 20, 34, 222, 368, 375
 - multilayer 378
 - nanosized 207
 - polymeric chain 220
 - three-dimensional 206
 - two-junction 408
 - valence 267
- substrate 13, 16, 140, 210, 218, 222, 225, 302, 303, 320, 322, 328, 329, 378, 380, 382, 387, 388
 - flexible 11, 12, 101
 - hot 322
 - solid 378
- surface 6, 8, 10, 15, 32, 83, 86, 87, 90, 139–141, 190, 205, 208–210, 214–223, 225, 226, 333
 - bare 86
 - flat 88, 223
 - hydrated 225
 - planar 386
 - solid 209
 - water 377, 378, 390
- surface Green's function 53–55, 57, 58
- SVD *see* singular value decomposition
- switches 233, 234, 244, 245, 250, 253, 254, 257, 264–267, 275, 277, 281, 284, 285, 289, 341, 342, 344, 345, 361, 362, 398
- conformational 263, 264
- controlled 236
- electronic 257, 398

- interlocked 263
- nano-electromechanical 234, 257
- switching barrier 265, 267, 271, 274, 278, 280, 284, 285, 290, 292
- switching behavior 245, 246, 264, 265, 268, 285
- switching events 234, 245, 266, 270, 271, 273, 275, 277, 288, 290–292, 294, 345, 362
- switching mechanisms 3, 234, 263–265, 267, 270, 275, 282, 288, 291, 292, 294
- switching pattern 266, 268, 270, 275, 286, 287
- switching rates 270, 273, 275, 277, 279, 284, 287–289, 291, 345
- systems 43–45, 47, 49, 50, 80, 81, 118–120, 122–124, 127, 128, 138, 145, 146, 177, 178, 286–288, 345–352, 355–359, 362–365, 399, 400
- acyclic 350, 359, 367
- biological 206, 342, 385
- bipartite 357, 358
- biphenyl 365, 366
- bistable 265, 284
- chemical 341, 342, 355, 359
- closed 46, 177
- complex 360
- coupled 39, 177, 184, 193, 194
- cyclic 348, 357–359, 365
- donor-bridge-acceptor 346
- electronic 69, 117, 145
- linker 135, 138
- macroscopic 208
- meta-substituted 352
- molecular-electronic 120, 142
- molecular-scale 142
- molecule-contact 318
- noninteracting 82
- nonmolecular 23
- self-assembled 208, 373
- solar 284
- stochastic 267
- superconducting 63
- synthetic 342
- toy 312
- technique 33, 37, 43, 50, 85, 94, 130, 131, 135, 140, 144, 319, 320, 322, 325, 328, 330, 331
- analytical 223
- atom manipulation 85
- break-junction 128
- calorimetric 331
- diffraction 219
- electromigration 5, 24, 25
- electrostatic trapping 381
- Green's function 122
- heuristic 32
- industrial fabrication 372
- lock-in 93
- microfabrication 208
- photolithographic 376
- recursive 50, 51, 53, 54
- scanning probe 5
- scanning-probe 372
- theory 31, 34, 40, 61, 72, 80, 83, 95, 103, 200, 203, 204, 303, 342, 347, 348, 420
- density-functional 2, 79
- functional 32, 157, 159, 202
- Green's function 40
- mechanical 37
- mobile adatom 222
- tight-binding 32, 72
- thermal conductance 302, 303, 305, 317, 318, 322, 332
- thermal transport 300, 308, 316, 317

- transistors 118, 148, 198, 233, 348, 372, 408, 410
 - single-molecule n-type 236
- transitions 33, 70, 71, 102, 163, 174, 185, 241, 264, 269, 271, 279, 280, 287, 288, 294, 414, 415
 - backward 291
 - ground-state 180
 - horizontal 104
 - inter-level 62
 - reverse 279–281
 - spin 21
 - triplet-to-singlet 170
 - vertical 163
 - vibrational 164, 166, 180, 188
- transition voltage spectroscopy (TVS) 133, 151
- transmission 46, 47, 54–56, 58, 59, 88, 89, 110, 186–188, 198, 309, 315, 345, 346, 348–354, 356, 360–362
 - elastic 100, 109, 188, 190, 193, 197
 - energy-independent 330
 - low-flat 354
- transmission function 55, 56, 59, 73, 308, 309, 311–314, 318, 332, 334
- transport 2, 3, 33, 34, 40, 42, 43, 50, 51, 53, 54, 79, 80, 117, 120, 121, 137, 156, 157, 172, 183–185, 278, 326
 - ballistic 304
 - elastic 80, 96, 184, 185
 - few-electron 398
 - inelastic 95, 97, 187, 201, 352
 - molecular 126
 - phonon 332
 - quantum-coherent 34
 - resonant 100, 190
 - single-electron 398
 - superexchange 121
- tunneling 8, 9, 15, 38, 40, 43, 120, 121, 127, 128, 130, 156, 203, 282, 284, 295, 398–417, 419, 420
 - coherent 348
 - mechanical 292, 399
- tunneling barriers 8, 9, 127, 209, 399
- tunneling electrons 42, 198, 278, 281, 290, 295, 400, 411–415
- tunneling event 189, 296, 400
- tunneling junction 367, 404, 406, 410–412, 415, 417
- tunneling rate 32, 33, 63, 66, 68, 274
- tunneling time 403, 404, 412, 413, 417
- tunnel junction 399, 402–411, 413, 415
- TVS *see* transition voltage spectroscopy
- vibrational excitations 3, 155–157, 163, 165, 175, 178, 180, 183–185, 202
- vibrational modes 102, 105, 107, 108, 155–157, 160, 161, 163–165, 170, 174, 176, 178, 180, 181, 183, 187, 189, 191
 - discrete 302
 - dominant 191, 192
 - dominant low-energy 182
 - longitudinal 108
 - multiple 167, 172
- vibrational quanta 161, 162, 170, 194
- vibrational spectroscopy 94, 105
- vibrational states 147, 195, 196, 295, 303
 - discrete 302
 - excited 178
- vibrations 34, 80, 95, 97, 106, 109, 110, 202, 278, 295, 321

- bouncing 295
- equilibrated 106
- intramolecular 284
- molecular 22, 93, 204, 265, 272, 293, 294
- phonons/atomic 303
- rolling 284
- WBL *see* wide-band limit
- wide-band limit (WBL) 54–56, 186, 188, 197

Single-molecule electronics has evolved as a vibrant research field during the last two decades. The vision is to be able to create electronic components at the highest level of miniaturization—the single molecule. This book compiles and details cutting-edge research with contributions from chemists, physicists, theoreticians, and engineers. It covers all aspects of single-molecule electronics, from the theory through experimental realizations and the chemical synthesis of molecular components to the implementation of molecular components in future integrated circuits. It describes in detail both established methods and recent advances in the field, including vibrational effects, switching phenomena, quantum interference, thermal power, and parallel assembly strategies. The authors add more details to the chapters than typically found in the primary literature so that the book can be read not only by specialists but also by non-experts and students with an interest in the research field. Each chapter is accompanied by problems, and a solutions manual is also provided.



Kasper Moth-Poulsen received his PhD in 2007 from University of Copenhagen, Denmark. He continued his career as a post doctoral scholar in Copenhagen (2007–2009) and at University of California, Berkeley (2009–2010) before joining Chalmers University of Technology, Gothenburg, Sweden, as an assistant (2011–2014) and associate professor (2014–). His research activities focus on nanomaterials chemistry, synthesis, and assembly of single-molecule electronic components and on development of methods for conversion and storage of solar energy.



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